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FT-790R MODEL CHART

MODEL FREQUENCY RANGE	FREQUENCY	PRESET	FREQUE	NCY STEP	REPEATER	
	FREQUENCY	SSB	FM	SHIFT (FM)	CALL FREQUENCY	
A	430 - 439.9999 ^{MHz}	436.000MHz	100Hz/1kHz	25kHz/100kHz	±5MHz	1800Hz
В	430 - 439.9999MHz	433,400MHz	100Hz/1kHz	25kHz/100kHz	-7.6MHz REV	1750Hz
с	430 - 439.9999MHz	433.400MHz	100Hz/1kHz	25kHz/100kHz	*1.6MHz REV	1750Hz
F	430 - 439.9999 ^{MHz}	433.000MHz	100Hz/1kHz	10kHz/100kHz	±SMHz	-

Note: Model F is for use in Japan only, and cannot be readily converted to other Models.

6.7 METER PORTABLE TRANSCEIVER



INTRODUCTION

The FT-790R is a fully portable, compact multi-mode transceiver for the 70 cm amateur band. Featuring PLL synthesis in 100 Hz, 1 kHz, 25 kHz, or 100 kHz steps, the FT-790R utilizes a Liquid Crystal Display for digital readout of the operating frequency. Ten memories, scanning of the band or memory channels, two VFOs, and receiver offset tuning make the FT-790R a significant breakthrough in technology.

Powered by eight "C" size dry cells or Ni-Cd batteries (not supplied), the FT-790R is completely self-contained and portable. A high-performance noise blanker is also included, for minimizing interference caused by impulse noise.

Power output is 1 watt, switchable to 0.2 watt for battery conservation. For memory backup purposes, a lithium cell is included, providing an estimated lifetime of five years because of the extremely low current consumption of the memory circuitry. The light weight, portability, and efficiency of the FT-790R make it suitable for field satellite operation, emergency FM work, or vacation enjoyment.

We recommend that you read this manual in its entirety, so as to understand more completely the many features of the exciting new FT-790R. With proper care in operation, this equipment will provide many years of reliable performance.

SPECIFICATIONS

GENERAL

Frequency coverage: 430.0 - 440.0 MHz Modes of operation: SSB (USB, LSB), CW and FM Synthesizer steps: SSB/CW: 100 Hz, 1 kHz FM: 25 kHz, 100 kHz Power requirements: 8 C - size dry battery cells or 8 C - size Ni-Cd battery cells External: 8 - 15V DC Memory backup: built-in lithium battery cell Current consumption: 100 mA on receive; (FM) 750 mA on transmit (1W RF, FM) Antenna impedance: 50 ohms Case size: 58(H) x 150(W) x 195(D) mm Weight: 1.3kg. without batteries

TRANSMITTER

Power output: 1 watt at 12 volts Carrier suppression: Better than 40 dB Spurious radiation: Better than -50 dB Unwanted sideband suppression: Better than 40 dB Tone burst frequency: 1800 Hz (A model) 1750 Hz (other models)

Frequency response: 300 - 2700 Hz (-6 dB) FM deviation: ±5 kHz Microphone impedance: 600 ohms

ICs:

FETs:

RECEIVER

Circuit type: SSB/CW: Double conversion superheterodyne FM: Triple conversion superheterodyne Intermediate frequencies: 1st IF 67.3 MHz 2nd IF 10.7 MHz 3rd IF 455 kHz (FM) Sensitivity: SSB/CW: 0.16µV for 10 dB S/N FM: 0.25µV for 12 dB SINAD Selectivity: SSB/CW: 2.4 kHz at 6 dB down; 4.1 kHz at 60 dB down FM: 12 kHz at 6 dB down: 25 kHz at 60 dB down Image rejection: Better than -60 dB Audio output impedance: 8 ohms Audio output: 1 watt @10% THD

RPT SHIFT

Model A ±5 MHz Model B -7.6 MHz, REV Model C +1.6 MHz, REV

SEMICONDUCTORS

:s:		Transistors:		Diodes:	
HD44820-A62	1	2SA733AP	7	1S188FM (Ge)	4
MC3357P	1	2SA1175E	3	1S1555 (Si)	3
MC14069UB	3	2SB548P	1	18853 (Si)	67
ND487C2-3R	1	2SC535B	6	1SS97	5
(Ring Module)		2SC945AP	21	(Schottky Barrier)	
TP0401	1	2SC1815GR	1	1T25 (Varactor)	1
µPC575C2	1	2SC2026	1	FC53M-4 (Varactor)	6
μPC577H	1	2SC2120Y	1	HZ4C3 (Zener)	1
μPC1037H	1	2SC2407	1	HZ6C2L (Zener)	1
μPC1170H	1	28C2570A	4	HZ7B1 (Zener)	1
μPD2819C	1	28C2785E	2	HZ9B2L (Zener)	1
TC-5082P	1	2SC3019	1	MV-11 (Varistor)	2
		2SC3020	1	TLG205 (LED)	1
ETs:				TLR205 (LED)	1
2SK168D	1			UOSB (Si)	1
2SK184Y	2			V06C (Si)	2
2SK192GR	1				
2SK193K	4			Liquid Crystal Display:	
2SK241GR	3			H1313A	1
3SK51-03	1				
38K73Y	3				
		Download	led b	y i	С. °,
		RadioAma	teur.	EU	

ACCESSORIES

Whip Antenna	(Q3000031)	
Microphone	(M3090033)	
Microphone Hanger	(R0071360)	
Shoulder Strap	(R7070600)	
External DC Plug	(P1090139)	
External Speaker Plug	(P0090034)	

Specifications subject to change without notice or obligation.

FRONT PANEL CONTROLS AND SWITCHES



(1) SQL

The squelch control silences the receiver in the FM mode when no stations are being received on the channel in use. The SQL control should only be advanced to the threshold point of background noise silencing; further advancing this control will lead to reduced sensitivity to weak signals.

(2) VOL

This is the audio gain control for the receiver, as well as the main ON/OFF switch for the transceiver.

(3) MODE

This selector determines the desired operating mode: LSB, USB, CW or FM. The __, <u>SIMP</u> and + positions select FM simplex or transmitter offsets for FM repeater operation. The + position is labelled <u>REV</u> in Model B, indicating that the transmit and receive frequencies are reversed. The __ position is labelled <u>REV</u> in Model C for the same reason.

(4) MAIN DIAL

The main tuning dial is used for selection of operating frequencies using the two main VFOs or the clarifier. In the LSB, USB, and CW modes, synthesizer steps of 100 Hz or 1 kHz are programmed, while on FM the channel steps are 25 kHz or 100 kHz each. In the clarifier mode, the synthesizer moves in 100 Hz steps.

(5) MR/PRI

This switch selects either the memory recall mode or priority channel operation. If only the MR/PRI switch is pressed, the memory channel selected by the MEMORY rotary switch will be activated. If the yellow F button is first pressed and then the MR/PRI button, priority channel operation will be selected.

(6) F

The yellow "F" (Function) button activates either the priority channel mode or the memory split mode. The F button itself does not select a mode, but it programs the microprocessor to select the mode labeled in yellow letters on either of the two switches immediately above the F button: DIAL/S or MR/PRI.

(7) STEP

This switch selects the desired synthesizer steps. In the LSB, USB, or CW mode, the preset mode* is 100 Hz per step. Press the STEP button to switch to 1 kHz steps. A second press of this switch returns you to 100 Hz steps. In the FM mode, the preset is for 25 kHz steps. Pressing the STEP switch selects 100 kHz steps, while a second press returns you to 25 kHz steps.

(8) VFO Switch

The VFO button selects one of the two internal VFOs on the FT-790R. Press the VFO switch to select VFO-B, and dial up the new frequency. A second press of the button releases the switch, returning you to VFO-A.

* When the lithium memory backup is on, switch-on (preset) conditions will be the same as when the transceiver was last switched off.

(9) CLAR

This switch activates the receiver offset tuning feature (Clarifier). The clarifier allows ± 9.9 kHz of offset from the transmit frequency, tuned in 100 Hz steps (all modes).

(10) M

The M (Memory) button is used to store a frequency in memory.

(11) MIC

This seven pin jack accepts microphone audio input, the scanning control lines, and the PTT (Push to Talk) control line. Microphone impedance is 500 ohms.

(12) MEMORY

The memory channel selector is used to choose any of the 10 memory channels. In the MS (Memory Scan) position, scanning of the memories may be performed.

(13) CALL

When this button is pressed (FM mode only), an 1800 Hz tone will be superimposed on the microphone line, and the PTT switch line will be grounded, activating the transmitter. This allows manual-length access of repeaters requiring a burst tone.

(14) ON AIR

This indicator lights up while transmitting.

(15) BUSY

This indicator lights up when the main squelch is opened up by an incoming signal.

(16) DIAL/S

When the DIAL/S button alone is pushed, tuning is accomplished by the main dial on either VFO-A or VFO-B. If the F button is pushed and then the DIAL/S button, the memory split mode will be selected; for receiving on the memory while transmitting on the VFO.

(17) DIGITAL DISPLAY

The digital display uses an LCD for indication of the operating frequency and mode. The frequency readout displays the last five digits of the operating frequency, with resolution to 0.1 kHz. Indicators are also provided for indication of clarifier operation ("CLAR"), priority channel operation ("P"), memory channel operation ("M"), or memory split operation ("-" on transmit).

(18) S/PO METER

The meter allows determination of incoming signal strength and relative power output. The meter is also used for checking battery condition.

(19) ANTENNA

The ANTENNA jack is a BNC type connector for quick connection of the rubber flex antenna or an external antenna.



REAR APRON SWITCHES AND JACKS



(1) KEY

This jack is used for the keying input line. Use a miniature phone plug for connection to your telegraph key or keyer. The key-up voltage is 7V, and the key-down current is 0.3 mA.

(2) LAMP/BATT

With this switch in the LAMP position, the front panel meter and display will become illuminated for nighttime operation. If the power switch (on the VOL control) is off, this lamp will stay off, thus preventing inadvertent battery discharge.

In the BATT position, the battery voltage is checked. The meter needle should deflect at least to the dividing line between the green and white zones of the meter scale. If not, the batteries require replacement or recharging.

(3) NB

This switch activates the built-in noise blanker. This blanker helps in minimizing pulse-type noise such as that caused by automotive ignition systems.

(4) HI/LOW

This switch selects power outputs of 1.0 watt (HI) or 0.2 watt (LOW).

(5) CASE LATCH

This mechanism provides easy opening and closing of the cabinet for battery replacement.

(6) EXT DC 13.8V

Use this jack for connection to an external DC supply. Never exceed 15 volts at this jack, and never apply AC power of any kind at this point. Also, be absolutely certain that DC power of the proper polarity is applied; when replacing DC plugs, check to be sure that the plug is wired correctly, as there is no standardized wiring polarity for the power plug used for the FT-790R. Failure to observe these simple precautions will void any and all warranties on this equipment.

(7) CHG

The external charge jack accepts charging voltage from the NC-11B/C battery charger (option). When using alkaline or other dry cell batteries, do not attempt to recharge them. Use only C size Ni-Cd cells (available from your Yaesu dealer) if you intend to recharge the cells.



SIDE PANEL JACKS



(1) STAND BY

This jack is wired in parallel with the PTT line of the microphone, allowing the use of a footswitch to activate the transmitter.

(2) EXT SP

Use this jack to connect an external speaker. The output impedance is 8 ohms.



SHOULDER STRAP ATTACHMENT AND REMOVAL

ATTACHMENT

REMOVAL



Press pin into hole, then pull up tab.



Press with thumb while lifting tab, swivel-ing back and forth slightly until pin disengages.

INTERNAL SWITCHES





(1) TONE SQ.

When the optional tone squelch unit is installed, this switch will place the unit in operation.

(2) SCAN

This switch selects automatic scan stop on a busy or clear channel, per your requirements. Manual scanning can also be selected, if desired.

(3) COMP

This switch activates the audio speech compressor for the SSB and FM modes. Average power in the SSB mode will be increased, with some loss of fidelity.

(4) BACKUP

This switch activates the lithium memory backup feature, and may be turned on and left on indefinitely.

See the Operation section for details.

ANTENNA CONSIDERATIONS

The FT-790R comes equipped with a 1/2 wavelength rubber flexible antenna, which should be sufficient for local work through repeaters, etc. Different types of antennas may be connected to the top panel BNC connector.

An external antenna must have an impedance of 50 ohms, and should be fed with good quality cable. If your current antenna has a connector which differs from the BNC type, consult your dealer regarding the purchase of a suitable adapter.

For base station use, gain antennas such as the yagi, quad, stacked vertical, etc., will enhance long distance communications. These antennas are also available from most Yaesu dealers.

BATTERY INFORMATION

The FT-790R is designed for use with eight size C Ni-Cd rechargeable cells or eight dry cells of the same size. When using alkaline cells or other dry cell types, no "dummy" battery is required, as the FT-790R will tolerate the slightly elevated voltage of these batteries as compared to Ni-Cd cells.

To install batteries, set the rear panel lever to OPEN to unlock the case. The bottom cover may then be carefully removed, exposing the battery holder. Install the eight new cells, being absolutely certain to observe the proper polarity.



WARNING

Serious damage can occur if incorrect battery polarity is used. Our warranty does not cover damage caused by incorrect polarity in the battery compartment.

MICROPHONES





Viewed from "A" Side

MICROPHONE PLUG CONNECTIONS

YM-47



If Ni-Cd cells are used, the optional NC-11B/C battery charger may be used to return the cells to a full charge. Allow the cells to discharge to the minimum operating voltage before recharging them. If the cells are only partially exhausted, and repeatedly recharged in this condition, they may develop a memory for this level, and not provide full discharge capability.

Ni-Cd cells suitable for use in the FT-790R are available from your Yaesu dealer. Ask also for the MMB-11 Mobile Mounting Bracket, FL-7010 Linear Amplifier, YM-49 and YM-50 microphones, and CSC-1A vinyl carrying case for the FT-790R.





FT-790R/MMB-11/YM-47/FL-7010



FT-790R/CSC-1/CSC-1A/YM-47

OPERATION

The tuning procedure for this transceiver is not complicated. However, because microcomputer circuitry is used extensively throughout the transceiver, this section should be read thoroughly, so as to understand all of the features that are made available. Note that off-frequency operation could occur without proper setting of the controls.

INITIAL CHECK

Before operating the transceiver, be certain that the necessary batteries are installed in the case, as described previously. If an external voltage source is used instead of batteries, confirm that the proper DC voltage is being applied to the rear panel jack, and that the proper polarity is used.

FREQUENCY READOUT

Frequency display is provided by a five-digit Liquid Crystal Display (LCD) system. Resolution of the last five digits of the operating frequency is provided to 0.1 kHz.

When operating on a memory channel, the letter "M" will appear on the left side of the display. The memory channel number is shown on the selector switch labeling, and the actual memorized frequency appears on the digital display.

FM OPERATION

Preset the controls and switches as described for SSB operation, but set the MODE switch to FM/SIMP.

Rotate the SQL (Squelch) control fully counterclockwise. Now turn the VOL control out of the click-stop to turn the transceiver on. Advance the volume control for a comfortable listening level.

When the channel is clear, adjust the SQL control so the background noise just disappears. This threshold point is the point of maximum sensitivity, and the squelch control should not be advanced beyond this point too far, or the squelch will pot respond to weak signals.

In the FM mode, the synthesizer steps provided are 25 kHz and 100 kHz per step (the clarifier steps are still 100 Hz/step). When you are changing modes from SSB to FM, and were last operating on other than a 25 kHz or 100 kHz step, the microprocessor will automatically move you to the next higher or lower 25 kHz or 100 kHz step upon the first click of the main tuning dial (or first stepping of the scanner).

Rotate the main tuning dial (or operate the scanning controls) until the desired frequency is reached. To transmit, close the PTT switch, and speak into the microphone in a normal voice. Release the PTT switch for receiver recovery.

For repeater operation, selection of the standard splits* is provided on the front panel. For -shift, set the MODE switch to FM/-, and for +shift, select FM/+. This selection can be made either during main dial or memory operation.

For operation on odd splits, use a combination of the memory system and the main tuning dial. First, store the desired receive frequency in any

* Standard splits for various models are shown in the Model Chart on the inside front cover of this manual, and additional details are given on page 4, item 3.

memory channel. Now use the main dial to select the desired transmit frequency. Next push the yellow F and S buttons. You will now be receiving on the memory channel just programmed. When you close the PTT switch, you will be transmitting on the main dial frequency. If you desire to listen on several memory channels, the memory channel selector may be rotated as desired.

The front panel CALL switch activates a manual-length 1750- or 1800 H_Z tone for repeater access. When this button is pushed, the transmitter is activated and the access tone is superimposed on the transmit signal.

CW OPERATION

- The synthesizer steps selected in the CW mode are identical to those used for SSB operation.
- (2) Connect a key to the rear panel KEY jack, using a miniature phone plug. The key-up voltage is 7V, while the key-down current is 0.3mA, so most electronic keyers that close completely to ground will work well with the FT-790R.
- (3) Set the MODE switch to CW.
- (4) Close the PTT switch on the microphone to switch to the transmit mode. If desired, a footswitch may be used with the FT-790R. The STAND BY jack, located on the side of the transceiver, is wired in parallel with the PTT line on the microphone. This may be used in situations where the microphone is not the most efficient means of activating the transmitter.
- (5) The clarifier may be used for following unstable signals. The clarifier allows offset tuning in 100 Hz steps away from the transmit frequency. See the section on clarifier operation for details.

SSB OPERATION

Preset the controls and switches as follows:

VOL		OFF (Fully counterclockwise)
SQL		Fully counterclockwise
MODE		Desired mode, USB or LSB
MEMO	RY	Channel 1
LAMP	(Rear apron)	OFF
NB	("")	OFF
HI/LOW	V (" , ")	HI
	2	

Rotate the VOL switch out of the click-stop, and adjust the volume level for comfortable audio output from the speaker. The display will indicate the operating frequency. When the transceiver is switched OFF, the lithium backup feature will ensure that the transceiver retains the frequency, step and mode (dial or memory) last used.

The STEP switch is used to select the desired synthesizer step, 1 kHz or 100 Hz per step (SSB/CW modes). If you rotate the main tuning dial, initially the synthesizer will provide 1 kHz steps. Press the STEP button once, and you will note that the steps are now 100 Hz (0.1 kHz) each. Another pressing of the STEP button will return the selection to 1 kHz/step.

Rotate the main tuning dial until an SSB signal is heard. Using the 100 Hz/ step mode, tune in the signal until a natural reproduction of the voice signal is obtained.

To transmit, close the microphone PTT switch, and speak at a normal level into the microphone. Release the PTT switch for receiver recovery. The microphone amplifier gain is preset in this transceiver and requires no adjustment for normal operation. If the station you are in contact with begins to drift, you may follow the station by activating the receiver offset tuning control (CLARIFIER). Push the CLAR button, and then rotate the main tuning dial (or push the scanning controls) until the desired frequency is reached. In the CLAR mode, the synthesizer automatically is set to the 100 Hz/step mode, and the STEP button is disabled. The clarifier leaves the transmit frequency unchanged.

Push the CLAR button again to return to normal operation with the clarifier off. If you switch the clarifier on again, the receiver will not return to the last offset frequency, but rather will initiate on the current operating frequency.

For satellite operation, it is possible for the transmit frequency to be varied while transmitting.

If pulse-type noise is encountered, the rear apron NB (Noise Blanker) switch may be activated. The FT-790R noise blanker is helpful in reducing interference caused by pulse noise such as that produced by automobile ignition systems.

To reduce power for local communication, place the HI/LOW power switch in the LOW position. In this position, the PEP output power is approximately 200 mW. Battery consumption will be greatly reduced by using the low power position whenever possible.

CLARIFIER OPERATION

Offset tuning is provided on receive, for tracking of unstable or Dopplershifted signals. The clarifier may be used either on VFO frequencies or memory frequencies.

To activate the clarifier, push the CLAR button once. The letters "CLAR" will appear on the digital display. Now, tune the receiver as needed to follow the unstable signal. The synthesizer automatically programs 100 Hz steps for clarifier operation. A frequency shift of up to 10 kHz can be accomplished by using the clarifier.

When you close the PTT switch, the digital display will revert to the frequency programmed before the clarifier was switched on. In other words, your transmit frequency has remained unchanged, while your receive frequency has been varied.

A second press of the CLAR button will cancel clarifier operation. If the CLAR button is then pressed again, switching the clarifier back on, the clarifier is zeroed to the original operating frequency (before any offset), not to the offset frequency tuned previously.

THE UP/DWN CONTROLS ON THE MICROPHONE MAY BE USED FOR SCANNING DURING CLARIFIER OPERATION.

VFO SELECTION

Two VFOs are available on the FT-790R for split frequency operation. The VFO selector button is the largest of the eight selector buttons on the front panel of the FT-790R. This switch is a push-push type, not the momentary type used for the other selector buttons.

For VFO B operation, push the VFO button once; the switch will hold inward, and the desired frequency may then be dialed up. Be certain, of course, that you are in the DIAL mode. To return to VFO A, simply push the VFO button again to release the switch. It is not possible to receive on one VFO while transmitting on another. For frequency splits of 10 kHz or less, use the clarifier to achieve this function. Otherwise, use the MEMORY SPLIT mode described elsewhere in this manual.

NOTE REGARDING BACKUP OPERATION

When a backup battery or main batteries are first installed in the FT-790R (after service or replacement), it is necessary to reset the microcomputer properly. Failure to follow a simple sequence of steps may cause erratic operation.

- Set both the VOL and memory backup switches (memory backup switch is located inside the cabinet, as shown on page 11) to OFF.
- (2) Replace the memory backup battery and main batteries (if removed).
- (3) Turn the VOL control out of the click-stop, turning the transceiver ON.
- (4) Now turn the backup switch to ON. The CPU is now reset, and the backup switch may be left on indefinitely, owing to the very low current drain in the backup mode.

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MEMORY OPERATION

Ten memory channels are available for storage and recall of favorite operating frequencies. The procedure for entry and recall of memory channels is extremely simple.

Push the DIAL switch for normal tuning, using the main tuning dial. When you have found a frequency you wish to store in memory (for example 432.525 MHz), rotate the MEMORY switch to 1 (channel 1) and push the M (memory store) button. If you wish to store 438.500 MHz in channel 2, rotate the main dial to that frequency, rotate the MEMORY switch to channel 2, push M, and so forth. This procedure may be repeated for all 10 memory channels.

To recall these frequencies, push the MR button (memory recall) and rotate the MEMORY switch to select the desired channel. One push of the MR button will keep you on memory recall operation until the DIAL button is pushed again to return you to main dial tuning. Note that there is no formal erasure procedure for memory channels. When you push the M button, the previous frequency stored in that position will be erased. Until a frequency is programmed into a memory channel (from initial switch on of the transceiver), 436.000 MHz (or 433.4 MHz) will be preset in all memory channels.

SCANNER OPERATION

The UP/DWN scanning controls on the microphone may be used to control the operating frequency.

When in the DIAL mode, one push of the UP button will cause the frequency to advance upward by one step of the synthesizer (the step size being programmed by the mode switch and the STEP button). If you hold the UP button down for more than 1/2 second, the scanner will become engaged, and you will begin scanning up the band. Push the UP or DWN button or the PTT switch to halt the scan.

Scanning toward a lower frequency is achieved by using the same procedure, only using the DWN button on the microphone.

To scan only the memory channels, rotate the MEMORY selector to either of the MS (Memory Scan) positions, and press the MR button. Now, when you push and hold the UP or DWN button, the scanner will search the memory channels only. Manual halting of the scan is accomplished by pushing the UP, DWN, or PTT switches as before.

Inside the case of the radio, the SCAN switch allows selection of one of three scan halt modes. In the MAN (Manual) position, scanning is halted as discussed above. If the BUSY position is selected (see Page 11), the scanner will search until a busy channel (one occupied by a station strong enough to break the main squelch) is received. The scan will then pause on that frequency for five seconds. If you choose to stay on that frequency, press one of the scan control buttons or the PTT switch. While in the PAUSE mode, the decimal point farthest to the right will blink; when you push a button to halt the resumption of the scan, the blinking will stop.

To scan for a clear channel (one where the squelch does not open), set the SCAN switch to CLEAR. The scan will halt, and the decimal point will blink, as in the previous section. Press the UP, DWN, or PTT switch to cancel the pause/resume feature and hold on the frequency you stopped at.

Memory scan halting follows the same format as main dial scanning.

PRIORITY CHANNEL OPERATION

Priority channel operation uses a combination of the main dial VFO and the memory. It can be used in conjunction with the automatic scan stop feature of the microprocessor, if desired. The steps for priority channel operation are detailed below.

CIRCUIT DESCRIPTION

- (1) Program into memory the desired priority channel. Do not recall the channel at this time.
- (2) Dial up a basic operating frequency on the main VFO. This will be your main operation channel during priority channel operation.
- (3) Set the SCAN switch to BUSY or CLEAR, as desired.
- (4) Now push the yellow F button, followed immediately by a press of the MR/PRI button. The letter "P" will appear on the digital display, signifying priority channel operation. The display will then show the VFO frequency, with a flash every five seconds to the memory channel being checked for activity. When the memory channel is busy or clear (depending on your instructions), the scanner will halt on the memory channel. The pause/restart feature does not function in this mode; to restart, simply press the F and MR/PRI buttons again.
- (5) If the SCAN switch is set to the MAN position, the CPU will have no instructions for halting the scan. Simply press the DIAL or MR button to select the desired channel under this mode of operation. If you hit the PTT switch during manual priority channel operation, the checking of the priority channel will be delayed by five seconds.

MEMORY SPLIT OPERATION

The memory split operation mode is useful for covering unusual repeater splits or other occasions where the receive frequency may be fixed, but the transmit frequency is variable. In this mode, you receive on a memory channel, while transmitting on the VFO.

- (1) Store the desired receive frequency into a memory channel.
- (2) Dial up the desired transmit frequency on the main dial.
- (3) Now press the yellow F and DIAL/S buttons. You will be receiving on the memory, while transmitting on the VFO.
- (4) For transmitting purposes, either VFO A or VFO B may be used. Set the VFO selector as needed.

The following circuit description, together with the block diagram (insert), is intended to provide an understanding of the basic circuit functions of this transceiver. Refer to the schematic diagram for more specific circuit and component details.

RECEIVER

The incoming RF signal from the antenna jack is passed through a lowpass filter, antenna relay RL_{1001} and helical resonator CV_{1001} to RF amplifier Q_{1001} (2SC2570A). After amplification the signal is filtered by helical resonator CV_{1002} and applied to 1st mixer Q_{1002} (2SC2570A), which also receives the 1st local signal, resulting in a 1st IF signal at 67.3 MHz.

The 1st IF signal is passed through the bandpass filter composed of T_{1001} through T_{1003} , and then applied to 2nd mixer Q_{1003} (3SK51) along with the 78.025 MHz 2nd local signal, resulting in a 2nd IF signal at 10.7 MHz. This signal is passed through XF₁₀₀₁ (10M30B x 2), a matched pair of monolithic crystal filters, between which the partially filtered signal is sampled for the noise blanker, mentioned later. From XF₁₀₀₁ a portion of the signal is fed to FM IF amplifier Q₁₀₀₇ (2SK241GR), while another portion is fed to IF amplifier Q₁₀₀₉ (3SK73Y) for the other modes.

The noise sample signal from the middle of XF_{1001} is applied to noise amplifier Q_{1004} (μ PC577H), the output of which is rectified by D_{1003} and D_{1004} (1S188FM) to switch Q_{1006} (2SC945AP), which in turn biases Q_{1007} and Q_{1009} off for the duration of a noise pulse. A portion of the output of Q_{1004} is also rectified by D_{1001} and D_{1002} (1S188FM x 2) and then amplified by Q_{1005} (2SC945AP) to provide noise blanker AGC back to Q_{1004} .

During FM operation, the amplified 2nd IF signal from Q_{1007} is applied to the mixer section of Q_{1008} (MC3357P), where the signal is mixed with a 10.245 MHz 3rd local signal generated within Q_{1008} from crystal X_{1001} . The 455 kHz resulting signal is passed through ceramic filter CF₁₀₀₁, and then back into the limiter amplifier section of Q_{1008} , which amplifies the signal and removes variations in amplitude. From the limiter amplifier section the signal is fed to the discriminator section, which produces an audio output corresponding to frequency variations in the 455 kHz IF signal.

When no carrier is present in the 455 kHz IF, the high frequency noise at the discriminator output, which is passed through a highpass filter, is amplified by the noise amplifier section of Q_{1008} and detected by D_{1005} (1S1555), producing a DC voltage. This voltage is fed to the squelch switch section of Q_{1008} , which biases off Q_{1022} (2SC945P) to interrupt the audio signal between the discriminator section of Q_{1008} and the AF amplifier. The squelch switch section of Q_{1008} also controls scan switch Q_{7001} (2SC945P) on SW Unit B, which then informs the microprocessor on the Control Unit of signal conditions on the operating frequency for automatic scanning and tone squelch "BUSY" control functions.

When a carrier is present in the 455 kHz 3rd IF, the noise no longer appears at the discriminator and the audio amplifier then receives the voice signal from the discriminator, while the microprocessor is informed that the channel is busy. The SQL control on the front panel sets the threshold level of the noise quieting required to activate squelch switching.

SSB and CW signals in the 10.7 MHz 2nd IF are amplified by Q_{1009} and passed through crystal filter XF₁₀₀₂ to amplifiers Q_{1010} and Q_{1011} (3SK73Y) before being applied to balanced demodulator Q_{1012} (μ PC1037H) and AGC detectors D_{1024} (1S188FM) and D_{1025} (1SS97). Q_{1012} is also fed with a carrier signal from carrier oscillator Q_{1015} (2SC535B), and thus produces an audio output which is passed to the audio amplifiers.

The AF amplifier consists of preamplifier Q_{1023} (2SC945P), lowpass filter Q_{1024} (2SC945P) and audio power module Q_{3005} (μ PC575C-2). The FM audio from squelch switch Q_{1022} or the SSB/CW audio from Q_{1012} is amplified by Q_{1023} and then filtered by Q_{1024} , where the audio above 3 kHz is cut off. The audio is then delivered to Q_{3005} on the AF Unit, where it is boosted to approximately 1 watt to drive the speaker.

The portion of the SSB/CW signal from Q_{1011} rectified by D_{1024} and D_{1025} is then fed to DC amplifier Q_{1018} (2SC1815GR), the output of which is applied to gate 2 of the MOSFETs in the IF amplifier chain. A portion of this AGC signal is buffered by Q_{1020} (2SK184Y) and amplified by Q_{1021} (2SA1175SE) for delivery to the meter for S-unit indication during reception.

TRANSMITTER

The audio input signal from the microphone is amplified first by Q_{1025} (μ PC1170H), which also acts as an audio compressor when switched by Q_{7002} (2SC945P). The output of Q_{1025} is then applied to amplifier Q_{1026} along with the burst oscillator tone from Q_{3007} (TC5082), if activated from the Call switch via Q_{3006} (2SA733P). The audio is then further amplified by Q_{1027} (2SC945P) and filtered of components above 3 kHz by Q_{1028} (2SC945P) before delivery to switch Q_{1030} (2SC2120Y) for FM, and switch Q_{1031} (2SC945P) for SSB. Q_{1026} , Q_{1027} and Q_{1028} all are switched off by Q_{1029} (2SA733P) during CW operation.

SSB

When the SSB mode is selected, the amplified audio is passed through switch Q_{1031} to balanced modulator module Q_{1012} (μ PC1037H), which also receives the 10.7 MHz signal from carrier oscillator Q_{1015} (2SC535B), whose frequency is offset slightly for the selected sideband or mode. The resulting modulated IF output is passed through Q_{1013} (2SC2785E) during SSB transmission, and then the desired sideband is passed through 10.7 MHz crystal filter XF₁₀₀₂, where the unwanted sideband is removed. The resulting single sideband signal is then amplified by Q_{1010} (3SK73Y), which also receives an ALC control voltage. Output from Q_{1010} is delivered to the transmit mixer composed of Q_{1034} and Q_{1035} (2SK193K x 2), which also receives the 78 MHz local signal from local oscillator Q_{1032} (2SC535B) after buffering by Q_{1033} (2SC535B). The resulting 67.3 MHz output from the mixer is passed through a bandpass filter to buffer Q_{1036} (2SK241GR) and then delivered to the TX Unit (PB-2410, PB-2411).

On the TX Unit the signal is passed through a lowpass filter to mixer Q2002 (ND487C2-3R), which also receives a 362.7 - 372.7 MHz local signal after it has first been buffered by Q2001 (2SC2570A) and filtered by helical resonator CV2001 (CV370). The output of the mixer at the operating frequency is buffered by Q2003 (2SC2570A), filtered by helical resonator CV2002 (CV441B), and then buffered again by Q2004 (2SC2407) before being fed to driver Q2005 (2SC3019) and then TX RF amplifier Q2006 (2SC3020). The one watt output is then passed through a lowpass filter and delivered to antenna relay RL1001 on the Main Unit, followed by another lowpass filter, to the antenna. A sample of the RF output delivered from the TX Unit is fed to the, PO/ALC detector composed of D1068 - D1070, which provide a DC voltage for power output indication on the PO meter, and an ALC voltage for amplification by AGC/ALC amplifier Q1018 (2SC1815GR). The level of this detected ALC voltage applied to Q1018 is reduced by a variable resistor added to ground when the HI/LOW switch is set to the LOW position, and the amplified output of Q1018 is applied to IF amplifier Q1010 to regulate its gain, preventing overdriving of the TX amplifiers.

FM

During FM transmission the audio from the microphone amplifiers and lowpass filter is passed through switch Q_{1030} to varactor D_{1031} (FC52M) in the oscillator loop of Q_{1032} . The audio thus modulates the 78 MHz signal produced by this oscillator; the output of which is buffered by Q_{1033} (2SC535B) and then delivered to the transmit mixer composed of Q_{1034} and Q_{1035} mentioned earlier in the SSB transmission description. The remainder of the transmit signal path for FM is the same as that for SSB. When the CALL button is activated from the front panel, switch Q_{3006} , mentioned at the beginning of the Transmit description as activating burst oscillator Q_{3007} , also switches Call control Q_{1057} (2SC945P), which closes the PTT line, activating Q_{1058} (2SC945P) and relay RL₁₀₀₂ to switch the 6.8V DC supply from the receiver to the transmitter circuitry.

CW

The keying signal is applied to CW Keying Control gates in Q_{1049} (1/3 MC-14669UB), which operate Unlock (UL) switch Q_{1037} (2SC945P), biasing

transmit IF amplifier Q_{1010} and final exciter buffer Q_{1036} on when the key is closed. Carrier oscillator Q_{1015} generates the carrier signal at 10.7 MHz in the same way as for USB, and thus the carrier signal is allowed to pass through the transmit signal path in the same manner as SSB when the key is closed, except that audio is blocked by switch Q_{1031} . The keying signal is also applied to the Sidetone Control gate of Q_{1049} (1/6 MC14069UB), and then to the sidetone oscillator formed by two more gates of Q_{1049} , whose output is delivered to audio amplifier module Q_{3005} .

PLL Circuit

The PLL system employs a μ PD2819C (Q₁₀₄₄), which contains a programmable divider and latch, phase detector, and reference oscillator. The synthesis scheme allows tuning of the 10 MHz operating range of the transceiver in 100 Hz steps.

VCO (Voltage-Controlled Oscillator) Q_{1038} (2SK192GR) generates a signal at 120.8916 – 124.2216 MHz, which is buffered by Q_{1039} (2SK241GR). A portion of this signal is then multiplied by three at Q_{1040} (2SC2026), and passed through helical resonator CV₁₀₀₃ (CV370) for delivery to 1st receive mixer Q_{1001} , and final transmit mixer Q_{2002} after buffering by Q_{2001} and filtering by CV₂₀₀₁ on the TX Unit.

The other portion of the buffered VCO signal is further buffered by Q_{1041} (2SK168D) and applied to PLL mixer Q_{1042} (2SC535B), which also receives a 119.225 MHz signal from crystal oscillator Q_{1047} (2SC535B). The resulting 1.666 – 4.997 MHz mixer product is amplified by PLL IF amp Q_{1043} (2SC535B) and applied to the programmable divider section of Q_{1044} . This section is instructed by frequency dividing signals delivered from the Control Unit via the Latch section of Q_{1044} , and the divided output is then applied to the phase detector section of Q_{1044} , where the phase of the divided signal is compared with that of the 4.266 MHz crystal reference oscillator section. Any resulting phase difference causes a DC voltage to be fed through lowpass filters Q_{1045} (2SK184Y) and then Q_{1046} (2SC945P), after which the DC voltage is applied to varactor D_{1035} (1T25) in the VCO circuit to shift the VCO frequency slightly, thus correcting the phase difference between the VCO and the crystal reference oscillator.

ALIGNMENT

If the phase difference exceeds a correctable value as detected by the phase detector in Q_{1044} , an Unlock signal triggers Q_{1037} (2SC945P), which in turn biases off RX and TX IF amplifier Q_{1010} , as well as final exciter buffer Q_{1036} , thus preventing transmission from occurring when the PLL is not locked.

Control Unit

The essence of the control system is 4-bit microprocessor Q_{4001} (HD-44820A62), which processes all data for control of the operating frequency, display and special functions. Hex inverter Q_{4002} (MC14069UB) shapes the pulses from the photo-interrupter on the tuning dial before application to Q_{4001} . Hex inverter Q_{4005} (MC14069UB) serves various power, transmit disable and display clock functions. Q_{4006} , Q_{4007} and Q_{4008} (all 2SC945AP) are switches for BUSY, minus repeater shift and plus repeater shift, respectively. Display data is routed along with front panel switch I/O through the Keyboard Unit to display driver Q_{6001} (TP0401) on the Display Unit, which then feeds LCD DS₆₀₀₁ (H1313A).

This equipment has been carefully aligned and tested at the factory prior to shipment. If the instrument is not abused, it should not require other than the usual attention given to electronic equipment.

Service or replacement of a major component may require considerable realignment. Under no circumstances, though, should realignment be attempted unless the operation of the transceiver is fully understood, the malfunction has been carefully analyzed, and the fault has definitely been traced to misalignment rather than part failure. Service work must only be performed by experienced personnel using the proper test equipment.

Never align this transceiver without having a 50 ohm dummy load connected to the antenna jack. Troubleshooting using an antenna can result in misleading indications on the test equipment.

EQUIPMENT REQUIRED

- RF Signal Generator: Hewlett-Packard Model 8640B or equivalent with one volt output at 50 ohms and frequency coverage to 500 MHz
- Vacuum Tube Voltmeter (VTVM): Hewlett-Packard Model 410B or equivalent with an RF probe good to 500 MHz
- 3. Dummy Load/Wattmeter: Bird Model 43 with 3W UHF slug + UHF Dummy Load
- 4. AF Signal Generator: Hewlett-Packard Model 200AB or equivalent
- 5. IF Seeep Generator: capable of output at 10.7 MHz
- RF Sweep Generator: capable of output at 420 460 MHz
- 7. Oscilloscope: Hewlett-Packard Model 1740A or equivalent
- 8. FM Deviation Meter
- Precision Frequency Counter: Yaesu Model YC-500E or equivalent with resolution to 0.01 kHz and frequency coverage to 500 MHz





PLL CIRCUIT ALIGNMENT

The PLL circuit alignment procedure requires an environment in which the ambient temperature is held constant within the range of 15 to 30°C during alignment. The transceiver must also be thermally acclimatized to the ambient temperature of the alignment environment, so it should be allowed to sit at the alignment temperature for several hours before beginning alignment if it has been located in a very warm or cold environment.

VOLTAGE ADJUSTMENT

1.5.7 VDC

- (a) Connect the DC voltmeter between the cathode of D_{1060} and ground.
- (b) Adjust VR1012 for a reading of 5.7 VDC on the meter.

2. Battery Check

- (a) Apply 8.5 VDC from an external source to the EXT DC 13.8V terminal.
- (b) Set the LAMP/BATT switch to the BATT position and adjust VR_{3001} so that the meter deflects exactly to the dividing line between the white and green zones on the meter scale.

1. PLL Local and IF

- (a) Set the MODE selector to the FM position and tune the transceiver to 439.9999 MHz.
- (b) Connect the oscilloscope to R_{1163} and adjust T_{1020} for maximum amplitude on the scope.

2. VCV Line

- (a) With the transceiver tuned to the same frequency as above, connect the DC voltmeter to the top of R_{1173} and adjust L_{1011} for a reading of 5.0 volts on the meter.
- (b) Retune the transceiver to 430.0000 MHz and check the meter for a reading of about 1 volt.

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J3002

J3001

J3003

J3005

J3004

- 3. PLL Local Frequency
 - (a) With the MODE selector set to FM, tune the transceiver to 435.0000 MHz.
 - (b) Connect the oscilloscope to R₁₁₆₃ and adjust T₁₀₂₁ for maximum amplitude on the scope.
- 4. PLL Output BPF
 - (a) Disconnect P₁₀₀₁ and connect a 50 ohm resistor across the plug. Connect the RF probe of the VTVM across the resistor.
 - (b) With the transceiver tuned to 435.0000 MHz, adjust CV₁₀₀₃ for maximum reading on the VTVM.
 - (c) Tune the transceiver to 439.9999 MHz and check that the VTVM reading remains approximately the same.
- 5. PLL Local Frequency

With the transceiver set to the FM mode at 435.0000 MHz, connect the frequency counter to P_{1001} and adjust TC₁₀₀₆ for 367.6750 MHz on the counter.

78 MHZ LOCAL OSCILLATOR ALIGNMENT

- (a) Set the transceiver for FM operation at 435.0000 MHz, and preset VR₁₀₀₇, VR₁₀₁₀ and VR₁₀₁₃ to their center positions. VR₁₀₀₇ and VR₁₀₁₃ are realigned in the Transmitter Section, FM Deviation procedure.
- (b) Connect the RF probe of the VTVM to the cathode of D_{1033} , and adjust $T_{1012} T_{1014}$ for maximum deflection on the meter.
- (c) Now adjust T₁₀₀₄ for minimum deflection on the meter, which should be less than 70 mV rms.
- (d) Set the MODE selector to CW, transceiver frequency to 435.9993 MHz, and connect the frequency counter to the cathode of D₁₀₃₃. Now adjust L₁₀₀₉ for a reading of 78.0250 MHz on the counter.

- (e) Set the transceiver to 435.9992 MHz and adjust VR₁₀₁₀ for a reading of 78.0349 MHz on the counter.
- (f) Now recheck the voltage with the RF probe on the cathode of D₁₀₃₃, and repeat step (c) in the FM mode at 435.0000 MHz, if necessary.

RECEIVER ALIGNMENT

1. FM IF and Detector

- (a) With the MODE selector set to FM, connect the signal generator to gate 1 of Q₁₀₀₃ and set the SSG for 10.7 MHz low-level output with 1 kHz modulation at 3.5 kHz deviation.
- (b) Connect an external speaker to the EXT SP jack, and connect the oscilloscope across this speaker. Set the VOL control to its center position, and adjust the SSG output level for a comfortable listening level.
- (c) Adjust T₁₀₀₅, T₁₀₀₆ and T₁₀₀₈ for the purest possible sine wave of maximum amplitude and minimum noise. (This adjustment may also be made using a SINAD meter in place of the scope.)

2. SSB IF

- (a) With the MODE selector set to FM, connect the signal generator to gate 1 of Q_{1003} . Set the SSG output for 10.7 MHz low-level output with no modulation.
- (b) Adjust T₁₀₀₉, T₁₀₁₀ and T₁₀₁₁ for maximum S-meter deflection, while adjusting the SSG output level to maintain a useful range on the S-meter.
- 3. RF Stages
 - (a) Connect the sweep generator to the antenna jack, and the oscilloscope to the emitter of Q₁₀₀₂.
 - (b) Preset TC_{1001} for minimum capacitance, and adjust CV_{1001} and CV_{1002} to obtain the waveform of Figure 1 at maximum amplitude. TC_{1001} is readjusted in the next procedure.



Figure 1

4. 1st IF

- (a) Connect the signal generator to the ANT jack, and set the SSG for an unmodulated output at 435 MHz sufficient to produce a deflection of several S-units on the meter with the transceiver tuned to the same frequency.
- (b) Adjust TC_{1001} , $T_{1001} T_{1004}$, T_{1013} and T_{1014} for maximum S-meter deflection, reducing the SSG output level when required to keep deflection below S-9.

5. S-Meter

- (a) Set the MODE selector to CW and connect the SSG to the ANT jack. Set the SSG for 10 dB μ unmodulated output at the same frequency as the transceiver, 435 MHz. Adjust VR₁₀₀₄, if necessary, to obtain an S-meter reading of exactly S-9.
- (b) Disconnect the SSG from the ANT jack and adjust VR_{1003} to the threshold point just before that at which the S-meter begins to deflect (with no signal input).
- (c) Repeat steps (a) and (b).

6. Noise Blanker

- (a) With the MODE set to CW, connect the SSG to the ANT jack and set the SSG for 50 dB μ unmodulated output at the center frequency of the transceiver.
- (b) Connect the DC voltmeter to TP_{1002} , and adjust T_{1007} for minimum indication on the voltmeter.
- 7. Squelch
 - (a) Set the MODE to FM, and the SQL control to the 12 o'clock position.
 - (b) With no signal input, adjust VR₇₀₀₁ so that the squelch just closes off the noise.
- 8. Sidetone
 - (a) Set the MODE to CW, and the VOL control fully counterclockwise. Connect a key to the KEY jack.

(b) Depress the key and adjust VR₁₀₁₁ for comfortable sidetone volume. At the factory, this control is preset for 150 mV rms at the speaker terminals.

TRANSMITTER ALIGNMENT

The dummy load must be connected to the ANT jack on the transceiver at all times during the following procedures.

1. Exciter

- (a) Set the MODE selector to FM and the HI/LOW switch to HI power. Preset VR₁₀₀₂ fully clockwise, and preset VR₁₀₀₁, VR₁₀₀₅ and VR₁₀₀₉ to their center positions.
- (b) Disconnect P_{2002} from J_{1007} , and connect the RF probe of the VTVM to J_{1007} . Now key the transmitter and adjust $T_{1015} T_{1019}$ for maximum deflection on the VTVM.
- (c) Set VR₁₀₀₆ to its center position, and connect the audio generator to the MIC jack. Set the AG for 20 mV rms output at 1.5 kHz.
- (d) Set the MODE selector to USB, key the transmitter, and adjust TC₁₀₀₃ for maximum deflection on the VTVM.
- (e) Set the MODE selector to LSB, key the transmitter, and adjust TC₁₀₀₂ for maximum deflection on the VTVM.

2. Idling Current

- (a) With P₂₀₀₂ disconnected from J₁₀₀₇, preset VR₂₀₀₁ and VR₂₀₀₂ fully counterclockwise.
- (b) Remove P₂₀₀₃ from J₂₀₀₁, and connect the ammeter in its place. Key the transmitter and adjust VR₂₀₀₁ for a reading of 4.5 mA on the meter.
- (c) Remove P₂₀₀₄ from J₂₀₀₂ and connect the ammeter in its place. Key the transmitter and adjust VR₂₀₀₂ for a reading of 75 mA on the meter.
- (d) Reconnect P2002 to J1007, P2003 to J2001, and P2004 to J2002.

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3. RF Power Amplifier

- (a) With the MODE selector set to FM and the HIGH/LOW switch set to the LOW position, tune the transceiver to 435 MHz. Connect a wattmeter with the dummy load at the ANT jack.
- (b) Key the transmitter and adjust CV₂₀₀₁, CV₂₀₀₂, TC₂₀₀₄, TC₂₀₀₃ and TC₂₀₀₂ for maximum output power on the wattmeter.

4. SSB Carrier Point

- (a) With the MODE set to USB, connect the audio generator to the microphone jack, and set the AG for 1.5 kHz at a level sufficient to produce an output of 500 mW on the wattmeter.
- (b) Now tune the AG to 300 Hz and note the power output. Then tune the AG to 2700 Hz and again note the output.
- (c) Adjust TC_{1003} , if necessary, and repeat step B until the output at both 300 Hz and 2700 Hz is equal (less than 500 mW).
 - (d) Set the MODE selector to LSB and repeat the above steps, adjusting TC_{1002} , if necessary.

5. FM Frequency

- (a) Set the MODE selector to FM, and remove all microphone input.
- (b) Connect the frequency counter to TP_{1003} and adjust TC_{1004} to obtain a reading of exactly 10.70000 MHz on the counter.

6. CW Frequency

- (a) Perform the following step with the MODE selector set to CW, key connected to the KEY jack, and PTT switch closed.
- (b) With the frequency counter connected to TP_{1003} , depress the key and adjust TC_{1005} for a reading of 10.70070 MHz on the counter.

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7. HI/LOW Power

- (a) With the wattmeter and dummy load connected to the ANT jack and the transceiver set to the FM mode, set the HI/LOW switch (rear panel) to the LOW position.
- (b) Close the PTT line and adjust VR₁₀₀₂ for 250 mW (or as desired) on the wattmeter.
- (c) Now set the HI/LOW switch to HI, and adjust VR₁₀₀₉ for 1 watt output.

8. PO Meter Alignment

- (a) On the rear panel, set the LAMP/BATT switch to the OFF (center) position.
- (b) With the transceiver set for FM, HI power, adjust VR₁₀₀₅ to obtain PO meter deflection in the center of the green zone on the meter scale.

9. FM Deviation

- (a) Connect the test equipment to the transceiver as shown in Figure 2.
- (b) Set the MODE selector to FM, COMP switch OFF, and transceiver frequency to 435.0000 MHz.
- (c) Set the Audio Generator for a 1 kHz output at 25 mV rms to the MIC jack, and adjust VR₁₀₁₃ for maximum deviation. Now adjust VR₁₀₀₇ for ±4.5 kHz deviation.
- (d) Now reduce the AG output to 2 mV rms and check to ensure that deviation is $\pm 3 4$ kHz.

10. Carrier Balance

- (a) Temporarily short R₁₁₁₉ using a jumper wire. Set the MODE to USB.
- (b) Monitor the carrier output at the antenna jack on the spectrum analyzer or monitor receiver, key the transmitter, and adjust VR₁₀₀₁ for minimum carrier output.
- (c) Switch the MODE selector to LSB and back to USB, comparing the carrier levels of both modes and adjusting VR₁₀₀₁ for equal carrier nulling.

PARTS LIST

11. SSB Microphone Gain

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- (a) With the transceiver set to USB mode and the COMP switch OFF, connect the audio generator to the MIC jack and set for an output of 1.5 kHz at 1.5 mV.
- (b) Key the transmitter and adjust VR₁₀₀₆ for an output power of 800 mW.



Figure 2

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Symbol No.	Part No.	MAIN CHASSIS Description
aymbol No.	Part No.	TRANSISTOR
Q1	G3205480	2SB548P/Q/R
QI	P/Q/R	2003401/0/1
	PIQIK	
	-	DIODE
D3	G2090027	Si 1SS53
DI	G2090034	" U05B
D2	G2090211	" V06C
		RESISTOR
R2	J10246680	Carbon Composition 1/4W GK 68Ω
R1	J00215101	Carbon Film 1/8W VJ 100Ω
KI	100210101	
		POTENTIOMETER
VR1 (with S1)	J62800057	K12B61004-5N1211-5KB, 10KA
The (min bi)	10200007	1
		CAPACITOR
C1, 4, 06, 07	K10186102	Ceramic Disc 63WV B 0.001µF (RD870-1B102K63V)
C5	K40129011	Electrolytic 16WV 1000µF
		(16RE1000)
		SWITCH
S2	N0190111	SRN 2046N
S3	Q9000193	EWT-XDDS2050B
S4	N0190084	SRS101C
S5	N6090028	SSHP-23-05
S6, 7	N6090029	SSFYP-22-07
		127
		MEMORY SWITCH BOARD
PB-2240	F0002240	Printed Circuit Board
	C3001271	P.C.B. with S4
		SWITCH BOARD C
PB-2409	F0002409	Printed Circuit Board
	C024090A	P.C.B. with S5, 6, 7, R1, 2, C4, 6, 7
		CONNECTOR
J1, 7	P1090201	UK-0002

J2	P1090197	SG-8021
J3	P1090051	\$G-8512
J4	P0090190	HEC0630
J5	P0090241	FM214-7SS(A)
J6	P1090293	BNC-R(1)
	121	
		METER
M1	M0290023	T-22
		SPEAKER
SP1	M4090028A	VS-50Y
-		
		BATTERY HOLDER
	Q9000116C	C-12A with Wire
	Q9000117C	1.00
		PEAFETAN F
		RECEPTACLE
P1 (with wire)	T9302700	TMP-15DP
P2("")	T9204420A	XHP-5
P3("")	T9204421	XHP-3
P4 (" ")	T9204422	
P5 ("")	T9204423	XHP-5
P6(" ")	T9204424	XHP-7
P8("")	T9204425	XHP-2
P9("")	T9204426	XHP-4
P10(" ")	T9204427	XHP-7
P11("")	T9204428A	XHP-2
P12("")	T9204429	XHP-5
P13(" ")	T9204430A	XHP-10
P14("")	T9204431A	XHP-12
P15("")	T9204432	5208-11
Model A		
P15("")	T9204433	5231-08
Model B, F		
		PLUG
P2003, 2004	P1090249	EMCM0201 (with short wire)
	-	
		KNOB
	R3068750	FT-32T Main Tuning
	R3068780	FT-14K MODE, M.CH
	R3068790	FT-12K VOL
	R3068800	FT-16DS SQL
	R3062161	Push Button A FUNCTION
	R3056500	Push Button B VFO

		MAIN UNIT
Symbol No.	Part No.	Description
PB-2426A	F0002426A	Printed Circuit Board
	C024260A	P.C.B. with Components Model A
	C024260B	" Model B, C
		IC
Q1008	G1090145	MC3357P
Q1049	G1090126	MC14069UB
Q1004	G1090072	µРС577Н
Q1012	G1090101	μPC1037H
Q1025	G1090415	μPC1170H
Q1044	G1090237	μPD2819C
		FET
Q1041	G3801680D	2SK168D
Q1020, 1045	G3801840Y	2SK184Y
Q1020, 1045	G3801920G	2SK192GR
Q1034, 1035,	G3801930K/	2SK193K or F or P
1056	F/P	
Q1007, 1036, 1039	G3802410G	2SK241GR
Q1003	G4800510C	3SK51-03
Q1009-1011	G4800730Y	3SK73Y
		TRANSISTOR
Q1014, 1016,	G3107331P/	2SA733A P of Q
	Q	25215521 01 2
1017, 1029,	2	
1050, 1051,	G3111750E	2SA1175E
Q1019, 1021, 1054	GST11750E	ACCEL & FOR
Q1015, 1032,	G3305350B	2SC535B
1033, 1042,	00000000	
1043, 1042,		
Q1005, 1006,	G3309451P/	2SC945A P or Q
1022-1024.	0330345117	
1022-1024,	Q.	
1031, 1037,		
1046, 1052,		
1053, 1058 1057(A.B.C)		
1057(A,B,C)	G3318150G	2SC1815GR
	G3318150G G3320260	2SC1815GR 2SC2026

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Q1001, 1002	G3325701	2SC2570A	
Q1013, 1055	G3327850E	2SC2785E	
			1
		DIODE	
D1001, 1002,	G2001880F	Ge	1S188FM
1004, 1024			
D1005	G2015550	Si	1\$1555
D1003,	G2090027	**	1\$\$53
1006-1023,	Automotion and an ann		and a second
1026-1030,			
1033, 1034,			
1036-1039,	1.2		
1042-1059,	٤		
1063, 1064,			
1066, 1067,			
1071			
D1025,	G2090118	Schottky	1SS97
1068-1070		-	
D1035	G2090107	Varactor	1T25
D1031	G2090179	"	FC53M-4
	G2090180	"	FC53M-5
D1062	G2090227	Zener	HZ9B2L
D1061	G2090226		HZ4C3
D1065	G2090225	"	HZ6C2L
D1032, 1072	G9090017	Varistor	MV11
D1060	G2090211	Si	V06C
	1000	1.1	
		CRYSTAL	
X1006	H0102372	HC18/T	4.266 MHz
X1001	H0100720A	HC18/U	10.245 MHz
X1002	H0102466	HC18/T3P	
X1004	H0102465	HC18/T3P	and the second se
X1003	H0102467	RW18/ T3P	and the second se
X1005	H0102463A	HC18/T3P	The Public Publi
X1007(A,B,C)	H0102483	HC18/T3P	and the second se
VELOOI	-	CRYSTAL FI	LTER
XF1001	H1102027	10M30B	
XF1002	H1102064	XF-10.7LS	4
		OF DALLIO FU	750
CF1001	H3900204	CERAMIC FIL	LIEN .
C4 1001	13900204	LF-H15S	

		RESIST	OR			
R1105, 1187	J00215220		n Film	1/8W	VJ	22Ω
R1009, 1012, 1218	J00215560		**	**	"	56Ω
R1111, 1144	J00215680				**	68Ω
R1007, 1015,	J00215101		2000	"		1000
1042, 1043,						0.0748
1052, 1053,	1.1				10	
1057, 1058,						
1101, 1108,						
1120, 1125,						
1134, 1142,						
1145, 1150,						
1152, 1174,						
1181, 1208,						
1217						
R1006, 1113	J00215221			"		2200
R1149	J00215271				**	2700
R1046, 1096,	J00215331		S945	**		3300
1114, 1216						
R1039, 1169,	J00215391	"				3900
1206		5				-
R1001, 1026,	J00215471	**	**	**	**	4705
1139, 1154,						
1170, 1219,						
1220						
R1005	J10246471		Composition	"	GK	4705
R1034	J00215561		Film	200	VJ	5600
R1003, 1025,	¬J00215681					6800
1048	1000110001					
R1017, 1157	J00215821		**			8200
R1037, 1051,	J00215102	11.5	2107.11	1975	1989	lkΩ
1056, 1062,						
1123, 1136, 1147, 1160,						
1172, 1207						
R1119	J10246102		Composition	1/4W	GK	lkΩ
R1171	J00215122		Film	1/4W	VJ	1.2ks
R1028, 1029,	J00215152					1.5ks
1112, 1161						
R1168	J00215182	**				1.8ks
R1047, 1063,	J00215222	**				2.2ks
1075, 1100,						
1102, 1118						
1133, 1155						
R1088, 1115	J00215272					2.7ks
1137, 1138,	1000000000000000000000000000000000000		10 U			
1163	9 I					

40

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R1221	J10216332	the second s	Composition	1/8W	GK	3.3kΩ
R1185	J00215392	"	Film	**	VJ	3.9kΩ
R1016, 1036, 1074, 1086, 1211	J00215472		"	"		4.7kΩ
R1059, 1069, 1071, 1089, 1097, 1203, 1204	J00215562	44		1/8W	U)	5.6kΩ
R1021, 1067, 1110	J00215822	."	"	"		8.2kΩ
R1008, 1014, 1033, 1040,	J00215103			*		10kΩ
1044, 1060, 1061, 1073, 1084, 1087, 1091, 1104, 1109, 1121, 1126-1128,						
1131, 1140, 1141, 1146, 1191, 1212, (A,B,C) 1214, 1215		÷				
	J00215123		**			12kΩ
R1173	J10246123		Composition	1/4W	GK	12kΩ
R1065, 1079	J00215153		Film	1/8W	VJ	15kΩ
R1083, 1098, 1099, 1116, 1117, 1129	J00215183	3.413	**			18kΩ
R1032, 1093 1103, (A,B,C) 1210	J00215223		*	**		22kΩ
R1013, 1179	J00215273					27kΩ
R1194	J00215333				<u>n</u> .	33kΩ
R1011, 1019, 1020, 1027, 1031, 1049, 1054, 1064, 1066, 1068, 1070, 1072, 1076, 1077, 1090, 1124, 1143, 1192 1201, 1202, 1209, 1213	300215473	**				47kΩ

24400					
R1198	J00215563		"	**	56kΩ
R1092, 1132	J00215683		**	**	68kΩ
R1178	J00215823				82kΩ
R1002, 1004, 1010, 1038, 1080, 1094,	J00215104	" "	"		100ks
1130, 1148, 1151, 1156, 1165–1167, 1180, 1193, 1196					
R1199, 1200	J00215154		**	**	150ks
R1153, 1159	J00215184			**	180ks
R1162	J10246184	" Composit	ion 1/4W	GK	180ks
R1023, 1081, 1082, 1095, 1135, 1184, 1197	J00215224	" Film	1/8W	VJ	220kΩ
R1035	J00215274			**	270ks
R1050, 1055	J00215334		1		330ks
R1122	J00215394				390k£
R1024, 1106, 1188, 1189	J00215474		"		470ks
R1205	J00215684		"	**	680ks
R1018, 1041, 1164, 1190	J00215105		"		1ΜΩ
R1078	J02245225		1/4W	SJ	2.2M
R1022, 1085	J02245335		"	**	3.3Ms
101001	J51752105	RGS6-FAN-1M	1M	0	
VR1001 VR1002, 1005, .1011	J51752503	RGS6-FAN-50k	50k	in the second se	
VR1003, 1009	J51752203	RGS6-FAN-20k	20k	Ω	
VR1004	J51752104	RGS6-FAN-100k			
VR1006	J51745222	H0651A009-2.2k		ΩB	
VR1012	J51745472	H0651A011-4.7		ΩB	
VR1007, 1013	J51745103	H0651A013-10K		ΩB	
VR1010	J51745223	H0651A015-22K		ΩB	
TRIDIO		100011010 201			-
		THERMISTOR			
TH1001	G9090013	25D29			1000
TH1002	G9090008	31D26		-	

	1.	CAPACITOR		
C1135, 1143, 1236	K00179001	Ceramic Disc 50WV (DD104SL0R5C50V02)	SL	0.5pF
C1011, 1017, 1168, 1172, 1237	K00172010	(DD104SL010C50V02)		1pF
C1164	K02179003		СН	2pF
	K00172030	(DD104CK020C50V02)		3pF
C1081, 1146, 1160	K02179004	(DD104SL030C50V02)	**	3pF
C1002	K 02172040	(DD104CH040C50V02)		4pF
C1027, 1030, 1156	K02172050	(DD104CH050C50V02)	.,	5pF
C1171	K00172050	(DD104SL050C50V02)	SL	5pF
C1003	K00173060	(DD104SL060D50V02)		6pF
C1152	K02173060	(DD104CH060D50V02)	CH	6pF
C1153, 1154	K06173060	(DD104UJ060J50V02)	IJ	6pF
C1001	K02173070	(DD104CH070D50V02)	СН	7pF
C1162	K07183080	" " 63WV (RD870-1N150-8R0D63V)	PH	8pF
C1194	K06173080	" " 50WV (DD104UJ080D50V02)	UJ	8pF
C1133	K00173080	(DD104SL080D50V02)	SL	8pF
C1155	K06173090	(DD104UJ090J50V02)	UJ	9pF
C1018, 1020, 1040, 1142, 1144	K00173100	(DD104SL100D50V02)	SL	10pF
C1137, 1138	K02173100	(DD104CH100D50V02)	CH	10pF
C1204	K05173100	(DD104RH100D50V02)	RH	10pF
C1157	K02175120	(DD104SL120J50V02)	CH	12pF
C1013	K00175150	(DD104SL150J50V02)	SL	15pF
C1163	K07185150	" " 63WV (RD870-1N150-150J63V)	/ PH	15pF

C1004, 1016	K00175220	Ceramic Disc 50W (DD104SL220J50V02)	V SL	22pF
C1005	K00175270	(DD104SL270J50V02)	"	27pF
C1070, 1072, 1076, 1195	K06175330	(DD104UJ330J50V02)	UJ	33pF
C1181, 1182	K00175330		SL	33pF
C1036	K06175390	(DD104UJ390J50V02)	UJ	39pF
C1007, 1032, 1057, 1083, 1249, 1251, 1255	K00175470	" " " " " " " " " " " (DD104SL470J50V02)	SL	47pF
C1074	K06179009	(DD105UJ560J50V02)	IJ	56pF
C1177, 1178	K00175560	(DD104SL560J50V02)	SL	56pF
C1196	K06185680	(RD871-1N750-680J63V)	w UJ	68pF
C1037, 1079, 1129, 1130	K06185101	(RD871-1N750-101J63V)	w	100pF
C1044, 1082	K00175101	(DD105SL101J50V02)	VV SL	100pF
C1053, 1058	K10186221	(RD870-1B221K63V) 63W	VV B	220pF
C1078	K06185221	(RD873-2N750-221J63V)	UJ	220pF
C1222	K10186471	(RD870-1B471K63V)	B	470pF
C1014, 1015, 1033, 1043, 1052, 1054, 1062, 1068,	K10186102	(RD870-1B102K63V)		0.001µ
1069, 1071, 1073, 1075		 (3) 105/3631 		
1077, 1087-1092,				
1100, 1101,	_			
1103, 1104, 1106,				
(A,B,C)	1			
1109, 1111,				
1112,			1.5	
1123-1125,				
1127, 1128,	1			
1148-1151,				
1158, 1161,				

C1165, 1169,	K10186102	Ceramic Disc	63WV	в	0.001µF
1170, 1173		(RD870-1B102K63V)			
1183, 1192,	1				
1201, 1211-					
1215, 1217,					
1220, 1225,	1 1				
1226, 1228,					
1229, 1230					6
(A,B,C)					
1231-1235,					
1238-1240,					
1252					
C1008, 1009,	K14180103	. " "	* 5	FZ	0.01µF
1021, 1034,		(RD873-1FZ-103Z63V)			
1035, 1042,					
1080, 1132,					
1134, 1136,					
1139-1141,					
1145, 1147,					
1167. 1174.					
1175, 1179,					
1180, 1185,					
1188					
C1097, 1118	K19149003	Semiconductor Ceramic	25WV		0.0015µF
		(UAT04X152K-L05AE)			
C1096, 1117	K19149007				0.0033µF
		(UAT05X332K-L05AE)			
C1028	K19149009	ALL TOTAL TOTAL			0.0047µF
C11224	110140011	(UAT05X472K-L05AE)			0.0000
C1122*	K19149011	(UAT05X682K-L05AE)			0.0068µI
C1047 1005	K10140012	(UA105X682K-L05AE)			0.01.12
C1047, 1095,	K19149013				0.01µF
1205, 1208-		(UAT05X103K-L05AE)			
1210, 1221, C1085	K19149017				0.022µF
C1005	K1714901/	(UAT06X223K-L05AE)			0.02241
C1105, 1190	K19149019	(UATOGAZZSK-LUSAE)			0.033µF
	B17142017	(UAT08X333K-L45AE)			0.05541
C1010, 1019,	K19149021	(0410045554 14541)			0.047µF
1022-1026,	all all and all all all all all all all all all al	(UAT08X473K-L45AE)			on trail
1031, 1041,		(CA100A4/3K-L43AE)			
1048, 1049,					
1051, 1055.					
1056, 1059-					
1061, 1063-	1				
1066, 1094					

C1006, 1166, 1250, 1253, 1254	K23140005	Ceramic Chip (GR40W5R102M50V)	50WV	0.001µF
C1241-1243, 1246, 1247	K21170002	Feed through (ECKL1H-102PE)	50WV	0.001µF
C1093, 1114, 1115, 1120	K40179001	Electrolytic (50RC2-1)	50WV	lμF
C1050, 1086, 1098, 1099, 1102, 1115, 1119, 1131, 1184, 1216, 1218, 1219, 1223, 1227	K40129012	" (16RC2-10)	16WV	10µF
C1107	K40089005	" (ECE-A1CK10016V10)	6.3WV	22µF
C1116	K40109009	" (ECE-A1AK33010V33)	10WV	33µF
C1113, 1248	K40109002	" (10RE47)	5	47μF
C1224	K40129002	(16RE47)	16WV	47μF
C1159, 1176, 1189	K40109001	,, (10RE100)		100µF
C1038, 1039, 1045	K70167104	Tantalum (CS15E1V0R1M)	35WV	0.1µF
C1207	K70167474	" (CS15E1VR47)	**	0.47µF
C1084, 1121, 1206	K70147105	(CS15E1E010E)	25WV	1µF
C1126	K70127225	" (CS15E1C2R2M)	16WV	2.2µF
C1046, 1191	K70120001	 (489D475X0016B1)		4.7μF
C1110	K70080001	 (489D685X0006A1)	6.3WV	6.8µF
C1186	K70100003		10WV	10µF
C1029	K70080004	(489D226X0006C1)	6.3WV	22µF
C1108	K70080006	(489D476X0006D1)		47μF
		TRIMMER CAPACITOR		
TC1001	K91000059	ECVIZW04 x 53	4pF	
TC1002-1006	K91000029	ECVIZW20 x 53	20pF	

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1000	1	CAVITY	
CV1003	Q9000214	CV370	1 A 1
CV1001, 1002	Q9000114	CV441B	
		INDUCTOR	
L1012	L1190004	FL4HR68M	0.68µH
L1010, 1015	L1190005	FL4H1R0M	1µH
L1016, 1018	L1190014	FL4H100K	10µH
L1006	L1190023	FL5H220K	22µH
L1017	L1190017	FL5H102K	1mH
L1020	L1190090	LAL04102K-NA	1mH
L1001	L0020767		
L1002	L0020743		
L1004	L0021259		
L1007, 1008	L0021261		
L1009	L0021257		
L1011	L0190015		
L1013	L0020725		
L1014	L1020680		
L1019	L0020978		
L1021	L0020745B		
1			
		TRANSFORMER	
T1005-1007	L0021161		
T1010, 1015	L0021163		
T1009, 1011	L0021164		
T1001-1003,	L0021165		
1016-1019			1
T1008	L0020887	5MMC-044X	
T1004, 1012-	L0021256		
1014			
T1020, 1021	L0020345	113SN6146F	
	-		
		RELAY	
RL1001	M1190042	G4Y-152P	DC6.8V
RL1001	M1190042 M1190035	BR211CD006M	DC0.04
KE1002	M1190055	BR211CD000M	
	1	CONNECTOR	
J1001, 1002,	P1090255	TMP-JA	
1007		Reaction of the second s	
J1008	P1090210	TMP-JV	1
J1004, 1005	P0090192	B3B-XH-A	
J1003, 1006	P0090194	B5B-XH-A	
J1010	P0090195	B6B-XH-A	

J1009	P0090196	B7B-XH-A	-	
	1	+		
JP1001	T9204342			
JP1002	T9204343			
JP1003	T9204344			
JP1004	T9204345		1.20	
JP1005	T9204346			
JP1006	T9204347			
JP1007	T9204348	50	No.	1
JP1008	T9204349	13	1	
JP1009	T9204350A			
JP1010	T9204351		1.12	1.1.1.2
JP1011	T9204352			
JP1012	T9204353A			
			1.	1.95
	1	NO MERIALIZIA I	1.0	
TP1001-1003	0400000	TP TERMINAL		
TP1001-1003	Q5000036	TP-G MK1095		
			the second se	1.1
	1.2	section of the sectio		
			GL6	196, 196,
Sumbel No.	Part No.	TX UNIT	ion	
Symbol No.	Part No.	Descript		ात्र
Symbol No. PB-2410	F0002410	Descripti Printed Circuit Board	A Board	:
	F0002410 F0002411	Descripti Printed Circuit Board Printed Circuit Board		ा ता क
	F0002410 F0002411 C024100A	Descripti Printed Circuit Board Printed Circuit Board P.C.B. with Components	A Board	а) т.
	F0002410 F0002411	Descripti Printed Circuit Board Printed Circuit Board	A Board	ात) कि
	F0002410 F0002411 C024100A	Descripti Printed Circuit Board Printed Circuit Board P.C.B. with Components	A Board	() ()
	F0002410 F0002411 C024100A	Descripti Printed Circuit Board Printed Circuit Board P.C.B. with Components	A Board	(a) (b)
PB-2410 Q2004	F0002410 F0002411 C024100A C024110A G3324070	Descripti Printed Circuit Board Printed Circuit Board P.C.B. with Components " TRANSISTOR	A Board	(a)
PB-2410 Q2004 Q2001, 2003	F0002410 F0002411 C024100A C024110A	Descripti Printed Circuit Board Printed Circuit Board P.C.B. with Components " TRANSISTOR 2SC2407	A Board	(1) (1)
PB-2410 Q2004	F0002410 F0002411 C024100A C024110A G3324070 G3325700	Descripti Printed Circuit Board Printed Circuit Board P.C.B. with Components " TRANSISTOR 2SC2407 2SC2570A	A Board	ा त) क
PB-2410 Q2004 Q2001, 2003 Q2005	F0002410 F0002411 C024100A C024110A G3324070 G3325700 G3330190	Descripti Printed Circuit Board Printed Circuit Board P.C.B. with Components " TRANSISTOR 2SC2407 2SC2570A 2SC2570A 2SC3019	A Board	ा त) क
PB-2410 Q2004 Q2001, 2003 Q2005	F0002410 F0002411 C024100A C024110A G3324070 G3325700 G3330190	Descripti Printed Circuit Board Printed Circuit Board P.C.B. with Components " TRANSISTOR 2SC2407 2SC2570A 2SC2570A 2SC3019 2SC3020	A Board	
PB-2410 Q2004 Q2001, 2003 Q2005 Q2006	F0002410 F0002411 C024100A C024110A G3324070 G3325700 G3330190 G3330200	Descripti Printed Circuit Board Printed Circuit Board P.C.B. with Components " TRANSISTOR 2SC2407 2SC2570A 2SC2570A 2SC3019 2SC3020 DIODE ARRAY	A Board	
PB-2410 Q2004 Q2001, 2003 Q2005	F0002410 F0002411 C024100A C024110A G3324070 G3325700 G3330190	Descripti Printed Circuit Board Printed Circuit Board P.C.B. with Components " TRANSISTOR 2SC2407 2SC2570A 2SC2570A 2SC3019 2SC3020	A Board	
PB-2410 Q2004 Q2001, 2003 Q2005 Q2006	F0002410 F0002411 C024100A C024110A G3324070 G3325700 G3330190 G3330200	Descripti Printed Circuit Board Printed Circuit Board P.C.B. with Components " TRANSISTOR 2SC2407 2SC2570A 2SC2570A 2SC3019 2SC3020 DIODE ARRAY	A Board	
PB-2410 Q2004 Q2001, 2003 Q2005 Q2006 Q2002	F0002410 F0002411 C024100A C024110A G3324070 G3325700 G3330190 G3330200 G3330200 G3330200	Descripti Printed Circuit Board Printed Circuit Board P.C.B. with Components " TRANSISTOR 2SC2407 2SC2570A 2SC3019 2SC3020 DIODE ARRAY ND487C2-3R DIODE	A Board B Board	
PB-2410 Q2004 Q2001, 2003 Q2005 Q2006	F0002410 F0002411 C024100A C024110A G3324070 G3325700 G3330190 G3330200 G3330200 G2090135 G2090135	Descripti Printed Circuit Board Printed Circuit Board P.C.B. with Components " TRANSISTOR 2SC2407 2SC2570A 2SC3019 2SC3020 DIODE ARRAY ND487C2-3R	A Board B Board IS1555	
PB-2410 Q2004 Q2001, 2003 Q2005 Q2006 Q2002	F0002410 F0002411 C024100A C024110A G3324070 G3325700 G3330190 G3330200 G3330200 G3330200	Descripti Printed Circuit Board Printed Circuit Board P.C.B. with Components " TRANSISTOR 2SC2407 2SC2570A 2SC3019 2SC3020 DIODE ARRAY ND487C2-3R DIODE	A Board B Board	

		RESISTOR	and the second		
R2019	J00215100	Carbon Film	1/8W	VJ	10Ω
R2005	J00215270	** **	1.11	**	27Ω
R2002, 2008	J00215560				56Ω
R2015	J00215820	84 88			82Ω
R2018	J00215101	Carbon Composition	"	GK	100Ω
R2012	J00215121	" Film		VJ	120Ω
R2014	J00215391			"	3900
R2004, 2006	J00215471				470Ω
R2001, 2011	J00215102				1kΩ
R2021	J10216221	" Composition	**	GK	220Ω
		and an and a second			
	4				
	-	POTENTIOMETER			
VR2001	J51752102	RGS6-FAN-1k	1kΩ		
VR2002	J51752202	RGS6-FAN-2k	2kΩ	2	-
					-
		CAPACITOR			
C2012	K02179003	Ceramic Disc (DD104CK020C50V02)	50WV	СН	2pF
C2032	K02179004	(DD104CH030C50V02)		"	3pF
C2010, 2011, 2014	K02172040	(DD104CH040C50V02)			4pF
C2030	K02173060				6pF
		(DD104CH060D50V02)		-	
C2017	K02173070				7pF
		(DD104CH070D50V02)			10.12
C2004, 2031	K02175120			0.000	12pF
		(DD104CH120J50V02)			00 F
C2027	K02179008				20pF
Contractor and the second	-	(DD104CH200J50V02)			
C2001	K02175270	and the second designed and the second second	**		27pF
		(DD104CH270J50V02)		01	20.17
C2005, 2006	K00175390			SL	39pF
	-	(DD104SL390J50V02)		-	
C2007	K02175390			CH	39pF
		(DD105-257CH390J50V			
C2021	K02185390	(RD871-1NPO-390J63V)	63WV		39pF
C2003, 2008, 2009, 2013, 2015, 2018, 2020, 2022, 2024, 2026, 2029	K10186102	(RD870-1B102K63V)		В	0.001µH

C2033-2037	K21170002	Ceramic Disc (ECK-Y1H-102WE)	50WV	0.001µF
C2002	K23140005	Ceramic Chip (GR40W5R102M)	50V	0.001µH
C2016, 2019, 2023, 2025, 2028	K40129012	Electrolytic (ECEA1CK100)	16WV	10µF
		TRIMMER CAPACITOR		
TC2001	K91000059	ECV1ZW 04x53	4pF	
TC2004	K91000028	ECV1ZW 10x53	10pF	-
TC2002, 2003	K91000029	ECV1ZW 20x53	20pF	
		INDUCTOR		
L2001	L0020876			
L2002	L0020824			
L2003	L1020677			
L2004, 2005, 2009, 2012	L0021263		81 June	
L2006, 2013	L1020677			
L2007, 2014	L1020671			
L2008, 2011	L0021262			
L2010	L1020677	Territoria and the second		
L2015	L0021260	and the second se		
1.2016, 2017	L0020767		and the second s	
		TRANSFORMER		<u>KII</u>
T2001, 2002	L0190007	FKMA070PB01-BR		
		CAVITY		
CV2001	Q9000214	CV-370		
CV2002	Q9000114	CV-441B		1
		FERRITE BEADS		
FB2001-2004	L9190001	Ri 3x3-1		
		CONNECTOR		2.24
J2001, 2002	P0090248	EMCS0252M		
J2003	P1090255	TMP-JA		-
		TP TERMINAL		1
TP2001, 2002	Q5000036	TP-G MK1095		



SQUELCH PRESET ALIGNMENT POINTS METER (BATTERY CHECK),



TRANSMITTER SECTION ALIGNMENT POINTS



PLL SECTION ALIGNMENT POINTS

RECEIVER SECTION ALIGNMENT POINTS











